SUD23N06-31L

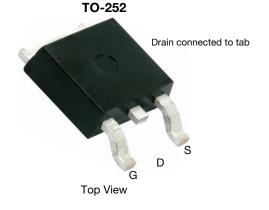


Vishay Siliconix

RoHS

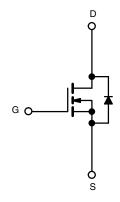
N-Channel 60 V (D-S), 175 °C MOSFET, Logic Level

| PRODUCT SUMMARY | | | |
|---------------------|---------------------------------|---------------------------------|--|
| V _{DS} (V) | R _{DS(on)} (Ω) | I _d (A) ^a | |
| 60 | 0.031 at V _{GS} = 10 V | 23 | |
| | 0.045 at V_{GS} = 4.5 V | 19.5 | |



FEATURES

- TrenchFET[®] power MOSFET
- 175 °C junction temperature
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



N-Channel MOSFET

Ordering Information: SUD23N06-31L-E3 (lead (Pb)-free)

| ABSOLUTE MAXIMUM RATINGS ($T_c = 25 \degree C$, unless otherwise noted) | | | | | |
|--|-------------------------|-----------------------------------|----------------|----|--|
| PARAMETER | SYMBOL | LIMIT | UNIT | | |
| Gate-Source Voltage | V _{GS} | ± 20 | V | | |
| Continuous Drain Current (T ₁ = 175 °C) ^b | T _C = 25 °C | | 23 | | |
| Continuous Drain Current $(1) = 175^{\circ}$ C) ² | T _C = 100 °C | I _D | 16.5 | | |
| Pulsed Drain Current | I _{DM} | 50 | А | | |
| Continuous Source Current (Diode Conduction) | I _S | 23 | | | |
| Avalanche Current | I _{AS} | 20 | | | |
| Single Avalanche Energy (Duty Cycle \leq 1 %) | L = 0.1 mH | E _{AS} | 20 | mJ | |
| Maximum Rower Dissinction | T _C = 25 °C | р | 37.5 | w | |
| Maximum Power Dissipation | T _A = 25 °C | P _D | 3 ^a | | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +175 | °C | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|--------------|-------------------|---------|------|------|
| PARAMETER | SYMBOL | TYPICAL | MAXIMUM | UNIT | |
| Maximum Junction-to-Ambient ^a | t ≤ 10 s | R _{thJA} | 18 | 22 | °C/W |
| Maximum Junction-to-Ambient ~ | Steady State | | 40 | 50 | |
| Maximum Junction-to-Case | | R _{thJC} | 3.2 | 4 | |

Note

a. Surface mounted on 1" x 1" FR4 board.

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SUD23N06-31L Vishay Siliconix



| SPECIFICATIONS (T _J = 25 °C, unless otherwise noted) | | | | | | |
|--|---------------------|---|------|-------------------|-------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. ^a | MAX. | UNIT |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | V_{GS} = 0 V, I_D = 250 μ A | 60 | - | - | v |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ | 1 | 2 | 3 | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$ | - | - | ± 100 | nA |
| | | $V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$ | - | - | 1 | μA |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} = 60 V, V_{GS} = 0 V, T_{J} = 125 °C | - | - | 50 | |
| | | V_{DS} = 60 V, V_{GS} = 0 V, T_{J} = 175 °C | - | - | 250 | |
| On-State Drain Current ^b | I _{D(on)} | $V_{DS} = 5 V, V_{GS} = 10 V$ | 50 | - | - | А |
| | | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 15 \text{ A}$ | - | 0.025 | 0.031 | |
| Drain-Source On-State Resistance b | Б | V_{GS} = 10 V, I_D = 15 A, T_J = 125 °C | - | - | 0.055 | Ω |
| Drain-Source On-State Resistance | R _{DS(on)} | V_{GS} = 10 V, I_{D} = 15 A, T_{J} = 175 $^{\circ}\text{C}$ | - | - | 0.069 | |
| | | $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 10 \text{ A}$ | - | 0.037 | 0.045 | |
| Forward Transconductance b | g fs | $V_{DS} = 15 \text{ V}, \text{ I}_{D} = 15 \text{ A}$ | - | 20 | - | S |
| Dynamic ^a | | | | | | |
| Input Capacitance | C _{iss} | | - | 670 | - | pF |
| Output Capacitance | C _{oss} | V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz | - | 140 | - | |
| Reverse Transfer Capacitance | C _{rss} | | - | 60 | - | |
| Total Gate Charge ^c | Qg | | - | 11 | 17 | |
| Gate-Source Charge ^c | Q _{gs} | V_{DS} = 30 V, V_{GS} = 10 V, I_{D} = 23 A | - | 3 | - | nC |
| Gate-Drain Charge ^c | Q _{gd} | | - | 3 | - | |
| Turn-On Delay Time ^c | t _{d(on)} | | - | 8 | 15 | |
| Rise Time ^c | tr | V_{DD} = 30 V, R_L = 1.3 Ω | - | 15 | 25 | |
| Turn-Off Delay Time ^c | t _{d(off)} | $I_D \cong 23$ A, V_{GEN} = 10 V, R_g = 2.5 Ω | - | 30 | 45 | ns |
| Fall Time ^c | t _f | | - | 25 | 40 | |
| Source-Drain Diode Ratings and Cha | aracteristics (| T _C = 25 °C) | | | | |
| Pulsed Current | I _{SM} | | - | - | 50 | А |
| Diode Forward Voltage | V _{SD} | $I_F = 15 \text{ A}, V_{GS} = 0 \text{ V}$ | - | 1 | 1.5 | V |
| Reverse Recovery Time | t _{rr} | I _F = 15 A, dl/dt = 100 A/μs | - | 30 | 60 | ns |

Notes

a. For design aid only; not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ISHAY www.vishay.com SUD23N06-31L

55 °C

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 $V_{GS} = 10 V$

4

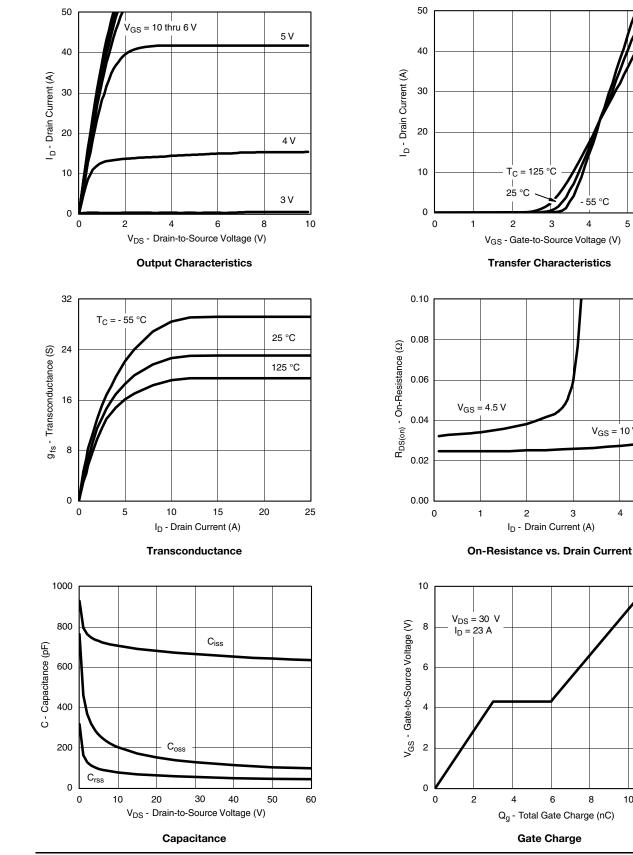
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



S14-2451-Rev. D, 15-Dec-14

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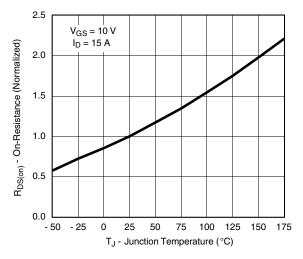
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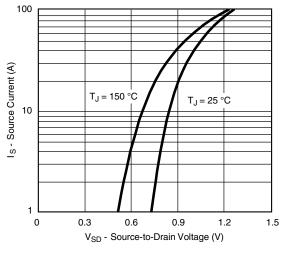
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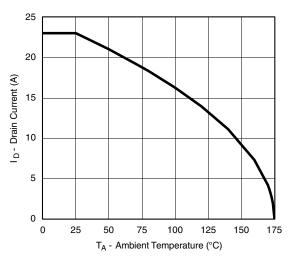
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



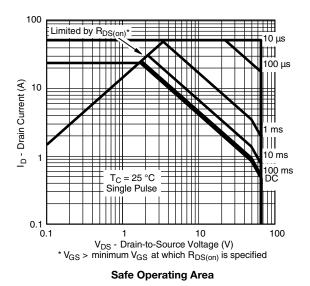
On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage



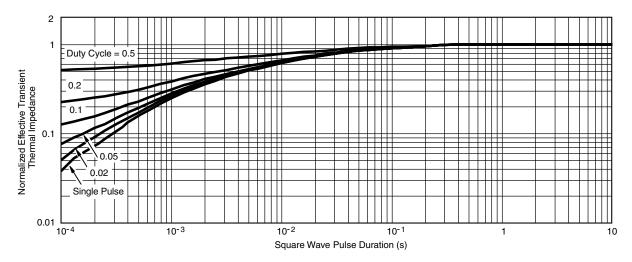
Maximum Drain Current vs. Ambient Temperature





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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

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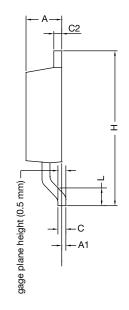


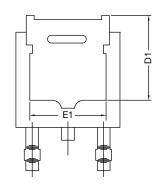


TO-252AA Case Outline

VERSION 1: FACILITY CODE = Y







| | MILLIMETERS | | | |
|------|-------------|----------|--|--|
| DIM. | MIN. | MAX. | | |
| А | 2.18 | 2.38 | | |
| A1 | - | 0.127 | | |
| b | 0.64 | 0.88 | | |
| b2 | 0.76 | 1.14 | | |
| b3 | 4.95 | 5.46 | | |
| С | 0.46 | 0.61 | | |
| C2 | 0.46 | 0.89 | | |
| D | 5.97 | 6.22 | | |
| D1 | 4.10 | - | | |
| E | 6.35 | 6.73 | | |
| E1 | 4.32 | - | | |
| Н | 9.40 | 10.41 | | |
| е | 2.28 | 2.28 BSC | | |
| e1 | 4.56 | 4.56 BSC | | |
| L | 1.40 | 1.78 | | |
| L3 | 0.89 | 1.27 | | |
| L4 | - | 1.02 | | |
| L5 | 1.01 | 1.52 | | |

Note

• Dimension L3 is for reference only



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VERSION 2: FACILITY CODE = N



| | MILLIMETERS | | |
|------|-------------|-------|--|
| DIM. | MIN. | MAX. | |
| А | 2.18 | 2.39 | |
| A1 | - | 0.13 | |
| b | 0.65 | 0.89 | |
| b1 | 0.64 | 0.79 | |
| b2 | 0.76 | 1.13 | |
| b3 | 4.95 | 5.46 | |
| С | 0.46 | 0.61 | |
| c1 | 0.41 | 0.56 | |
| c2 | 0.46 | 0.60 | |
| D | 5.97 | 6.22 | |
| D1 | 5.21 | - | |
| E | 6.35 | 6.73 | |
| E1 | 4.32 | - | |
| е | 2.29 BSC | | |
| Н | 9.94 | 10.34 | |

| | MILLIMETERS | | |
|------|-------------|--------|--|
| DIM. | MIN. | MAX. | |
| L | 1.50 | 1.78 | |
| L1 | 2.74 | l ref. | |
| L2 | 0.51 | BSC | |
| L3 | 0.89 | 1.27 | |
| L4 | - | 1.02 | |
| L5 | 1.14 | 1.49 | |
| L6 | 0.65 | 0.85 | |
| θ | 0° | 10° | |
| θ1 | 0° | 15° | |
| θ2 | 25° | 35° | |

Notes

• Dimensioning and tolerance confirm to ASME Y14.5M-1994

• All dimensions are in millimeters. Angles are in degrees

• Heat sink side flash is max. 0.8 mm

Radius on terminal is optional

ECN: E22-0399-Rev. R, 03-Oct-2022 DWG: 5347

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RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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